

SMS05C, SMS12C, SMS15C, SMS24C

5-Line Transient Voltage Suppressor Array

This 5-line voltage transient suppressor array is designed for application requiring transient voltage protection capability. It is intended for use in over-transient voltage and ESD sensitive equipment such as computers, printers, automotive electronics, networking communication and other applications. This device features a monolithic common anode design which protects five independent lines in a single SC-74 package.

Features

- Protects up to 5 Lines in a Single SC-74 Package
- Peak Power Dissipation – 350 W (8 × 20 μs Waveform)
- ESD Rating of Class 3B (Exceeding 8.0 kV) per Human Body Model and Class C (Exceeding 400 V) per Machine Model
- Compliance with IEC 61000-4-2 (ESD) 15 kV (Air), 8.0 kV (Contact)
- Flammability Rating of UL 94 V-0
- Pb-Free Package is Available

Applications

- Hand-Held Portable Applications
- Networking and Telecom
- Automotive Electronics
- Serial and Parallel Ports
- Notebooks, Desktops, Servers

MAXIMUM RATINGS (T_J = 25°C unless otherwise specified)

| Symbol | Rating | Value | Unit |
|-------------------|---|----------------------------------|------|
| P _{PK} 1 | Peak Power Dissipation 8 × 20 μs Double Exponential Waveform (Note 1) | 350 | W |
| T _J | Operating Junction Temperature Range | -40 to 125 | °C |
| T _{STG} | Storage Temperature Range | -55 to 150 | °C |
| T _L | Lead Solder Temperature (10 s) | 260 | °C |
| ESD | Human Body Model (HBM) Machine Model (MM) IEC 61000-4-2 Air (ESD) IEC 61000-4-2 Contact (ESD) | >8000 >400 >15000 >8000 | V |

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Non-repetitive current pulse per Figure 3.

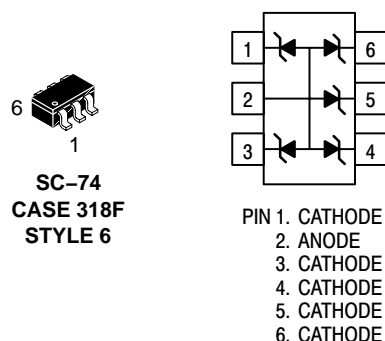


ON Semiconductor®

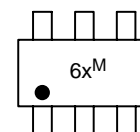
<http://onsemi.com>

SC-74 FIVE TRANSIENT VOLTAGE SUPPRESSOR 350 W PEAK POWER

PIN ASSIGNMENT



MARKING DIAGRAM



x = SMS05C:J
= SMS12C:K
= SMS15C:L
= SMS24C:M
M = Date Code

ORDERING INFORMATION

| Device | Package | Shipping† |
|-----------|--------------------|------------------|
| SMS05CT1 | SC-74 | 3000/Tape & Reel |
| SMS12CT1 | SC-74 | 3000/Tape & Reel |
| SMS15CT1 | SC-74 | 3000/Tape & Reel |
| SMS15CT1G | SC-74 (Pb-Free) | 3000/Tape & Reel |
| SMS24CT1 | SC-74 | 3000/Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

SMS05C, SMS12C, SMS15C, SMS24C

SMS05C ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|----------------------------|------------------|---|-----|-----|------|------|
| Reverse Working Voltage | V _{RWM} | (Note 2) | | | 5.0 | V |
| Breakdown Voltage | V _{BR} | I _T = 1.0 mA (Note 3) | 6.2 | | 7.2 | V |
| Reverse Leakage Current | I _R | V _{RWM} = 5.0 V | | | 5.0 | μA |
| Clamping Voltage | V _C | I _{PP} = 5.0 A (8 × 20 μs Waveform) | | | 9.8 | V |
| Clamping Voltage | V _C | I _{PP} = 24 A (8 × 20 μs Waveform) | | | 14.5 | V |
| Maximum Peak Pulse Current | I _{PP} | 8 × 20 μs Waveform | | | 24 | A |
| Capacitance | C _J | V _R = 0 V, f = 1.0 MHz (Line to GND) | | 260 | 400 | pF |

SMS12C ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|----------------------------|------------------|---|------|-------|-----|------|
| Reverse Working Voltage | V _{RWM} | (Note 2) | | | 12 | V |
| Breakdown Voltage | V _{BR} | I _T = 1.0 mA (Note 3) | 13.3 | | 15 | V |
| Reverse Leakage Current | I _R | V _{RWM} = 12 V | | 0.001 | 1.0 | μA |
| Clamping Voltage | V _C | I _{PP} = 5.0 A (8 × 20 μs Waveform) | | | 19 | V |
| Clamping Voltage | V _C | I _{PP} = 15 A (8 × 20 μs Waveform) | | | 23 | V |
| Maximum Peak Pulse Current | I _{PP} | 8 × 20 μs Waveform | | | 15 | A |
| Capacitance | C _J | V _R = 0 V, f = 1.0 MHz (Line to GND) | | 120 | 150 | pF |

SMS15C ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified) (See Note 4)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|----------------------------|------------------|---|-----|------|-----|------|
| Reverse Working Voltage | V _{RWM} | (Note 2) | | | 15 | V |
| Breakdown Voltage | V _{BR} | I _T = 1.0 mA (Note 3) | 17 | | 19 | V |
| Reverse Leakage Current | I _R | V _{RWM} = 15 V | | 0.05 | 1.0 | μA |
| Clamping Voltage | V _C | I _{PP} = 5.0 A (8 × 20 μs Waveform) | | | 24 | V |
| Clamping Voltage | V _C | I _{PP} = 12 A (8 × 20 μs Waveform) | | | 29 | V |
| Maximum Peak Pulse Current | I _{PP} | 8 × 20 μs Waveform | | | 12 | A |
| Capacitance | C _J | V _R = 0 V, f = 1.0 MHz (Line to GND) | | 95 | 125 | pF |

SMS24C ELECTRICAL CHARACTERISTICS (T_J = 25°C, unless otherwise specified)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|----------------------------|------------------|---|------|-------|-----|------|
| Reverse Working Voltage | V _{RWM} | (Note 2) | | | 24 | V |
| Breakdown Voltage | V _{BR} | I _T = 1.0 mA (Note 3) | 26.7 | | 32 | V |
| Reverse Leakage Current | I _R | V _{RWM} = 24 V | | 0.001 | 1.0 | μA |
| Clamping Voltage | V _C | I _{PP} = 5.0 A (8 × 20 μs Waveform) | | | 40 | V |
| Clamping Voltage | V _C | I _{PP} = 8 A (8 × 20 μs Waveform) | | | 44 | V |
| Maximum Peak Pulse Current | I _{PP} | 8 × 20 μs Waveform | | | 8.0 | A |
| Capacitance | C _J | V _R = 0 V, f = 1.0 MHz (Line to GND) | | 60 | 75 | pF |

2. TVS devices are normally selected according to the working peak reverse voltage (V_{RWM}), which should be equal or greater than the DC or continuous peak operating voltage level.
3. V_{BR} is measured at pulse test current I_T.
4. Parametrics are the same for the Pb-Free packages, which are suffixed with a "G".

SMS05C, SMS12C, SMS15C, SMS24C

查询"SMS15CT1"供应商 **TYPICAL PERFORMANCE CURVES** ($T_J = 25^\circ\text{C}$ unless otherwise specified)

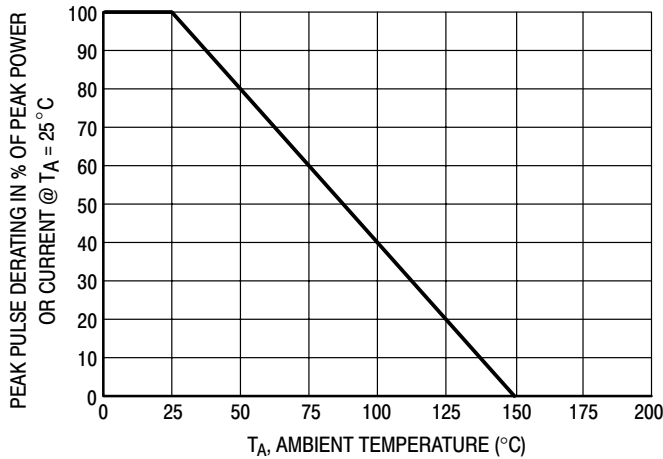


Figure 1. Pulse Derating Curve

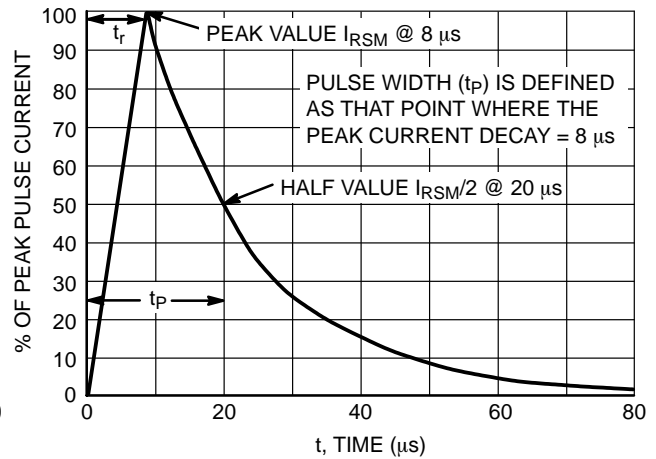


Figure 2. $8 \times 20 \mu\text{s}$ Pulse Waveform

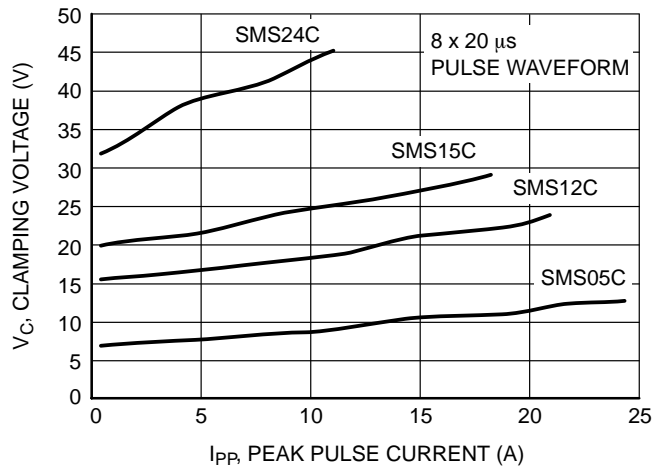


Figure 3. Clamping Voltage vs. Peak Pulse Current

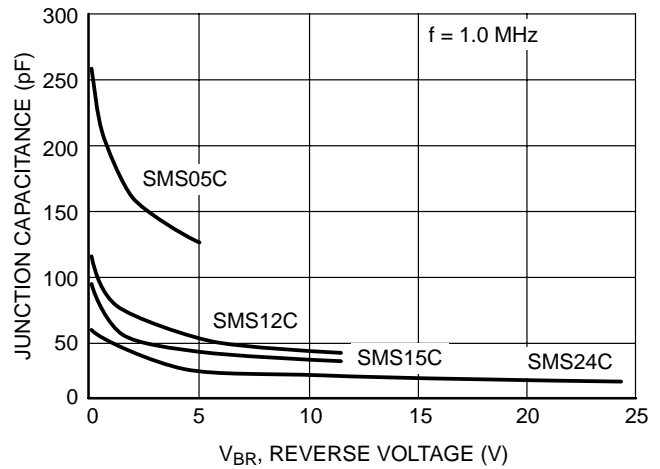


Figure 4. Junction Capacitance vs. Reverse Voltage

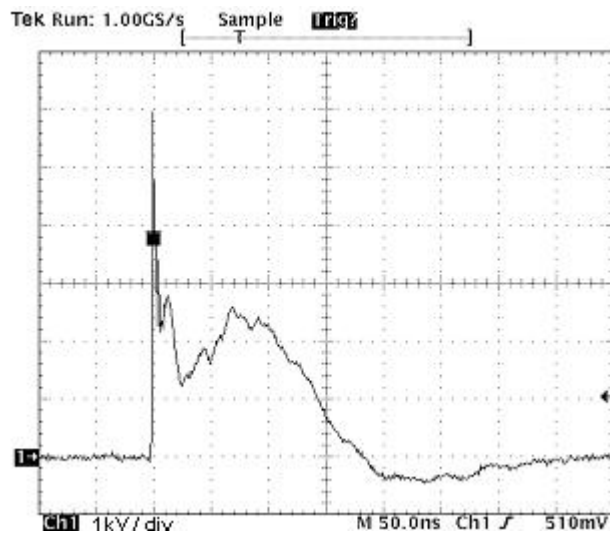


Figure 5. ESD Pulse IEC 61000-4-2 (8.0 kV Contact)

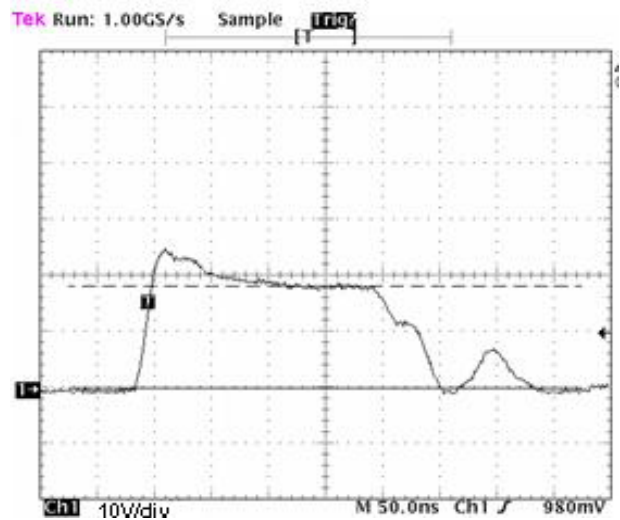


Figure 6. SMS15CT1 ESD Response for IEC 61000-4-2 (+8.0 kV Contact)

[查询"SMS15CT1"供应商](#)

TYPICAL COMMON ANODE APPLICATIONS

A 5 TVS junction common anode design in a SC-74 package protects four separate lines using only one package. This adds flexibility and creativity to PCB design especially

when board space is at a premium. A simplified example of SMS05C Series Device applications is illustrated below.

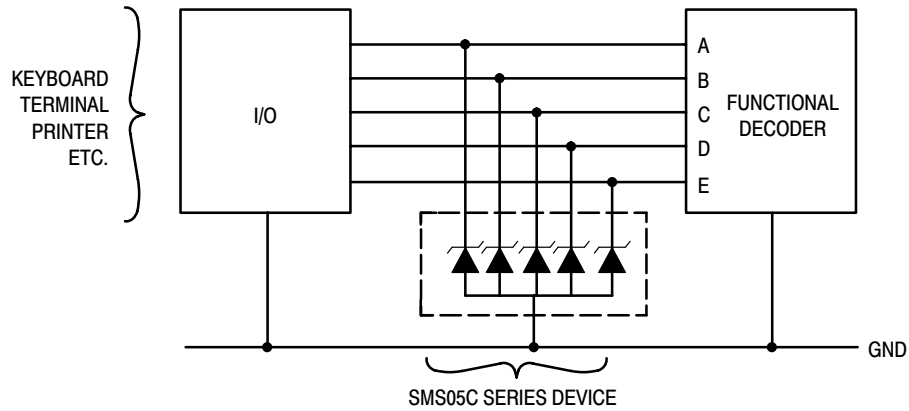


Figure 7. Computer Interface Protection

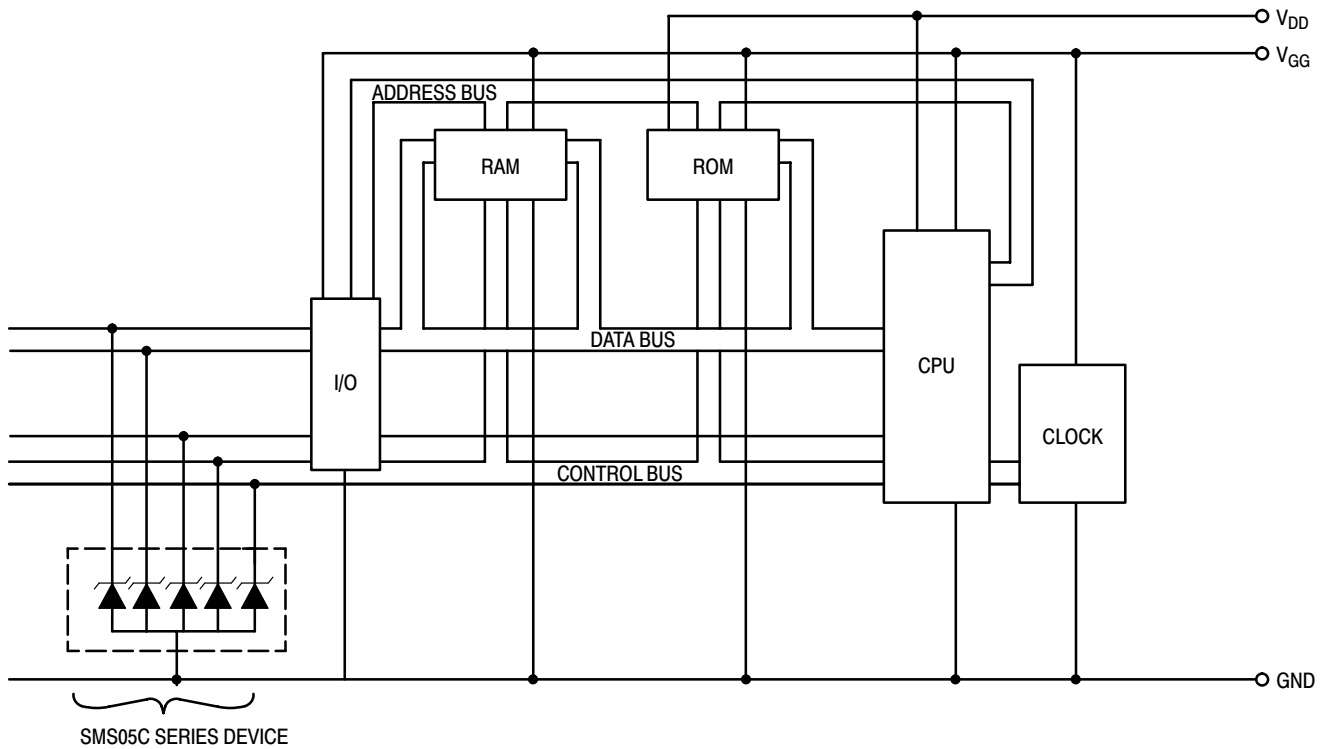


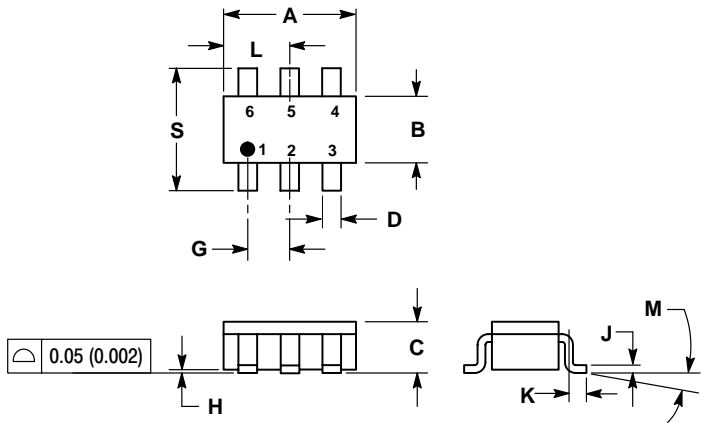
Figure 8. Microprocessor Protection

SMS05C, SMS12C, SMS15C, SMS24C

[查询"SMS15CT1"供应商](#)

PACKAGE DIMENSIONS

SC-74
CASE 318F-05
ISSUE K

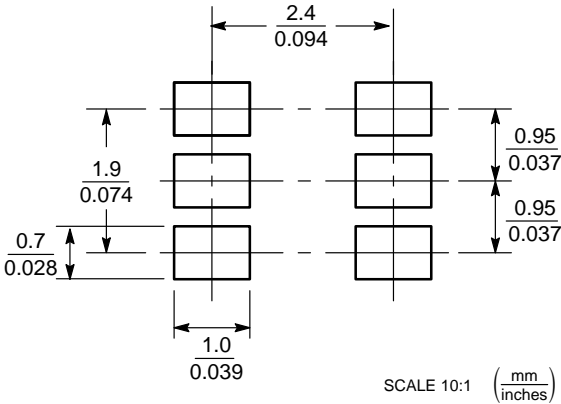


- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

| DIM | INCHES | | MILLIMETERS | |
|-----|--------|--------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | 0.1142 | 0.1220 | 2.90 | 3.10 |
| B | 0.0512 | 0.0669 | 1.30 | 1.70 |
| C | 0.0354 | 0.0433 | 0.90 | 1.10 |
| D | 0.0098 | 0.0197 | 0.25 | 0.50 |
| G | 0.0335 | 0.0413 | 0.85 | 1.05 |
| H | 0.0005 | 0.0040 | 0.013 | 0.100 |
| J | 0.0040 | 0.0102 | 0.10 | 0.26 |
| K | 0.0079 | 0.0236 | 0.20 | 0.60 |
| L | 0.0493 | 0.0649 | 1.25 | 1.65 |
| M | 0° | 10° | 0° | 10° |
| S | 0.0985 | 0.1181 | 2.50 | 3.00 |

STYLE 6:
PIN 1. CATHODE
2. ANODE
3. CATHODE
4. CATHODE
5. CATHODE
6. CATHODE


SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

SMS05C, SMS12C, SMS15C, SMS24C

[查询"SMS15CT1"供应商](#)

ON Semiconductor and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor
P.O. Box 61312, Phoenix, Arizona 85082-1312 USA
Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada
Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada
Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free
USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center
2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051
Phone: 81-3-5773-3850

ON Semiconductor Website: <http://onsemi.com>

Order Literature: <http://www.onsemi.com/litorder>

For additional information, please contact your
local Sales Representative.